TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL TYPE (PCT PROCESS)

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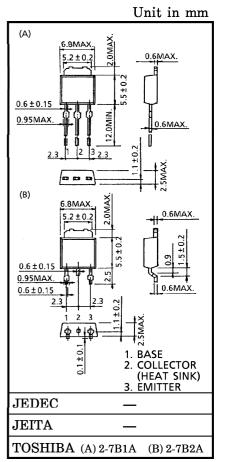
HIGH CURRENT SWITCHING APPLICATIONS

Low Collector Saturation Voltage
 : V_{CE} (sat) = 0.4 V (Max.) (at I_C = 3 A)

• High Speed Switching Time : $t_{stg} = 1.0 \,\mu s$ (Typ.)

MAXIMUM RATINGS (Tc = 25°C)

CHARACTI	SYMBOL	BOL RATING			
Collector-Base Voltage		v_{CBO}	100	V	
Collector-Emitter Voltage		V _{CEO}	80	V	
Emitter-Base Voltage		v_{EBO}	7	V	
Collector Current	DC	IC	5	A	
	Pulse	I _{CP}	8		
Base Current		$I_{\mathbf{B}}$	1	A	
Collector Power	$Ta = 25^{\circ}C$	Da	1.0	w	
Dissipation	$Tc = 25^{\circ}C$	$^{-}$ PC	20		
Junction Temperature		Tj	150	°C	
Storage Temperature Range		$T_{ m stg}$	-55~150	°C	



Weight: 0.36 g (Typ.)

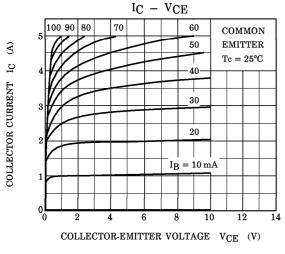
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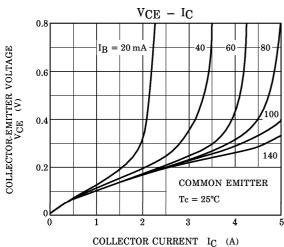
ELECTRICAL CHARACTERISTICS (Tc = 25°C)

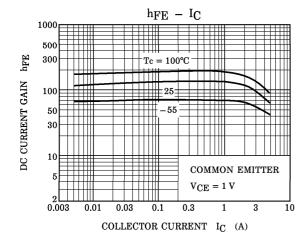
CHARAC	TERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off	Current	I_{CBO}	$V_{CB} = 100 \text{ V}, I_{E} = 0$	_	_	1	μ A
Emitter Cut-off Current		$I_{ m EBO}$	$V_{EB} = 7 \text{ V}, I_{C} = 0$	_	_	1	μ A
Collector-Emitter Breakdown Voltage		V (BR) CEO	$I_{\mathrm{C}}=10\mathrm{mA},~I_{\mathrm{B}}=0$	80	_	_	V
DC Current Gain		hFE (1) (Note)	$V_{ ext{CE}} = 1 \text{ V}, \text{ I}_{ ext{C}} = 1 \text{ A}$	70	_	240	
		h _{FE (2)}	$V_{CE} = 1 V, I_{C} = 3 A$	40	_	_	
Collector-Emitte Voltage	r Saturation	V _{CE} (sat)	$I_{\rm C} = 3~{\rm A},~I_{\rm B} = 0.15~{\rm A}$	-	0.2	0.4	V
Base-Emitter Sa	turation Voltage	V _{BE} (sat)	$I_C = 3 A, I_B = 0.15 A$	_	0.9	1.2	V
Transition Frequency		$ m f_{T}$	$V_{CE} = 4 V, I_{C} = 1 A$	_	120	_	MHz
Collector Output Capacitance		C_{ob}	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0,$ f = 1 MHz	l	80	_	pF
Switching Time	Turn-on Time	t _{on}	$I_{B1} \stackrel{IN-}{\longleftarrow} I_{B1} \stackrel{OUTPUT}{\longleftarrow} I_{B2} \stackrel{OUTPUT}{\longleftarrow} V_{CC} = 30 \text{ V}$	1	0.2	_	
	Storage Time	$t_{ ext{stg}}$		_	1.0	_	μs
	Fall Time	t_f	$I_{B1} = -I_{B2} = 0.15 \text{ A},$ DUTY CYCLE $\leq 1\%$		0.1	_	

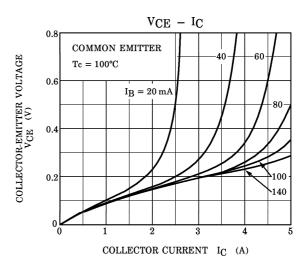
(Note) : hFE (1) Classification O : 70~140, Y : 120~240

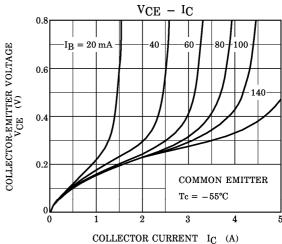
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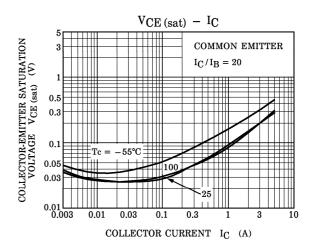




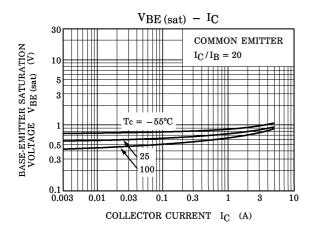


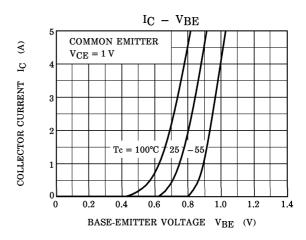


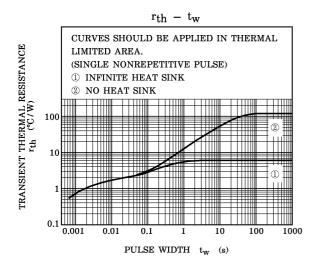


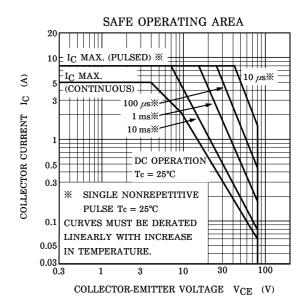


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